

FORM PTO-1449 (Substitute)

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Gou-Chung Chi et al.

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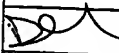
**U.S. PATENT DOCUMENTS**

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
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**FOREIGN PATENT DOCUMENTS**

	AL						
	AM						
	AN						
	AO						
	AP						

**OTHER PRIOR ART** (Including Author, Title, Date, Pertinent Pages, Etc.)

	AR	Planar GaN n <sup>+</sup> -p photodetectors formed by Si implantation into p-GaN J. K. Sheu, M. L. Lee, L. S. Yeh, C. J. Kao, C. J. Tun, M. G. Chen, G. C. Chi, S. J. Chang, Y. K. Su, and C. T. Lee Department of Physics, National Central University, Chung-Li 320, Taiwan, Republic of China (Received 6 May 2002; accepted 7 October 2002)					
	AS						
	AT						

EXAMINER

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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.